SK52C THRU SK5AC

SCHOTTKY BARRIER RECTIFIER Reverse Voltage - 20 to 100 V Forward Current - 5 A

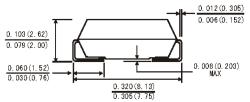
Features

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction, majority carrier conduction
- · For surface mount applications
- · Low power loss, high efficieny
- · High current capability, low forward voltage drop
- · Low profile package
- · Built-in strain relief, ideal for automated placement
- For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications

Mechanical Data

- Case: JEDEC SMC (DO-214AB) molded plastic body
- Terminals: solder plated, solderable per MIL-STD-750, method 2026
- · Polarity: color band denotes cathode end

<u>SMC(DO-214AB)</u> 0. 245 (6. 22) 0. 128 (3. 25) 0. 108 (2. 75) 0. 280 (7. 11) 0. 260 (6. 60)



Dimensions in inches and (millimeters)

Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, resistive or inductive load. For capacitive load, derate by 20%.

Parameter	Symbols	SK52C	SK53C	SK54C	SK55C	SK56C	SK58C	SK5AC	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	30	40	50	60	80	100	٧
Maximum RMS Voltage	V_{RMS}	14	21	28	35	42	57	71	٧
Maximum DC Blocking Voltage	V_{DC}	20	30	40	50	60	80	100	V
Maximum Average Forward Rectified Current 0.375"(9.5mm) Lead Length	I _{F(AV)}	5							Α
Peak Forward Surge Current, 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC method at Rated T _L)	I _{FSM}	150							А
Maximum Forward Voltage at 5 A ¹⁾	V_{F}	0.55			0.	75	0.8	0.85	٧
Maximum DC Reverse Current $T_a = 25 ^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_a = 100 ^{\circ}\text{C}$	I _R	0.5							- mA
Typical Junction Capacitance 3)	CJ	500			400				pF
Typical Thermal Resistance ²⁾	$R_{ heta JA} \ R_{ heta JL}$	55 10							°C/W
Operating Junction Temperature Range	T _J	- 65 to + 125							°C
Storage Temperature Range	Ts	- 65 to + 150							°C

¹⁾ Pulse test: 300 µs pulse width, 1% duty cycle

²⁾ P.C.B mounted 0.55 X 0.55" (14X14mm) copper pad areas

³⁾ Measured at 1 MHz and applied reverse voltage of 4 V

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FIG. I-FORWARD CURRENT DERATING CURVE

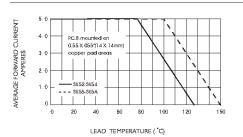


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

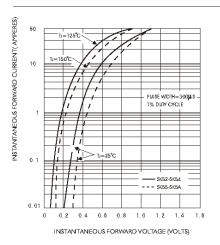


FIG.5-TYPICAL JUNCTION CAPACITANCE

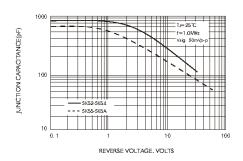


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

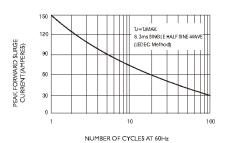


FIG.4-TYPICAL REVERSE CHARACTERISTICS

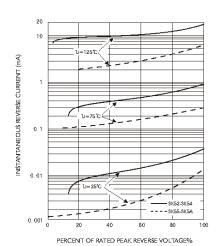


FIG.6-TYPICAL TRANSIENT THERMAL IMPEDANCE

